

Dual Switching Diode Common Cathode

MAXIMUM RATINGS (EACH DIODE)

Rating	Symbol	Value	Unit	
Reverse Voltage	V _R	100	Vdc	
Recurrent Peak Forward Current	IF	200	mAdc	
Peak Forward Surge Current (Pulse Width = 10 μsec)	I _{FM(surge)}	500	mAdc	
Power Dissipation @ T _A = 25°C Derate above 25°C	P _D ⁽¹⁾	625 5.0	mW mW/°C	
Operating and Storage Junction Temperature Range	T _J , T _{stg} ⁽¹⁾	-55 to +135	°C	

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ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted) (EACH DIODE)

Characteristic	Symbol	Min	Max	Unit
Breakdown Voltage (I _(BR) = 100 μAdc)	V _(BR)	100	_	Vdc
Reverse Current $(V_R = 100 \text{ Vdc})$ $(V_R = 50 \text{ Vdc})$ $(V_R = 50 \text{ Vdc})$ $(V_R = 50 \text{ Vdc}, T_A = 125^{\circ}\text{C})$	I _R	_ _ _	5.0 0.1 50	μAdc
Forward Voltage (I _F = 1.0 mAdc) (I _F = 10 mAdc) (I _F = 100 mAdc)	V _F	0.55 0.67 0.75	0.7 0.82 1.1	Vdc
Capacitance (V _R = 0)	С	_	1.5	pF
Reverse Recovery Time $(I_F = I_R = 10 \text{ mAdc}, V_R = 5.0 \text{ Vdc}, i_{rr} = 1.0 \text{ mAdc})$	t _{rr}	_	4.0	ns

^{1.} Continuous package improvements have enhanced these guaranteed Maximum Ratings as follows: $P_D = 1.0 \text{ W} \ @ T_C = 25^{\circ}\text{C}$, Derate above $25^{\circ}\text{C} - 8.0 \text{ mW/}^{\circ}\text{C}$, $T_J = -65 \text{ to } +150^{\circ}\text{C}$, $\theta JC = 125^{\circ}\text{C/W}$.

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TYPICAL CHARACTERISTICS

Curves Applicable to Each Anode

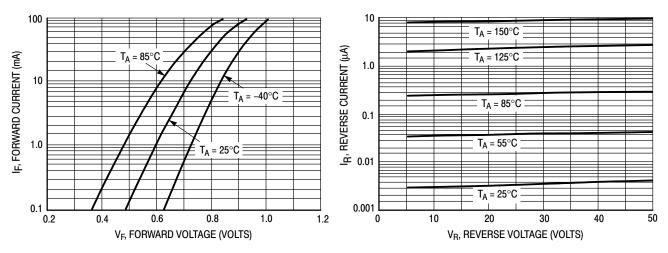


Figure 1. Forward Voltage

Figure 2. Leakage Current

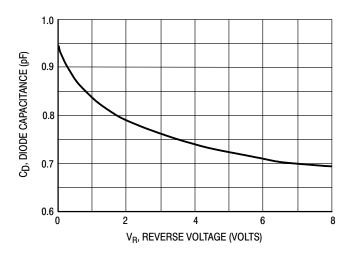
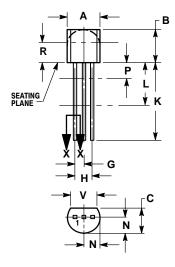


Figure 3. Capacitance

PACKAGE DIMENSIONS

TO-92 (TO-226AA) CASE 29-11 ISSUE AL





STYLE 3:
PIN 1. ANODE
2. ANODE
3. CATHODE

- NOTES:
 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
 2. CONTROLLING DIMENSION: INCH.
 3. CONTOUR OF PACKAGE BEYOND DIMENSION R IS UNCONTROLLED.
 4. LEAD DIMENSION IS UNCONTROLLED IN P AND BEYOND DIMENSION K MINIMUM.

	INCHES		MILLIN	IETERS
DIM	MIN	MAX	MIN	MAX
Α	0.175	0.205	4.45	5.20
В	0.170	0.210	4.32	5.33
С	0.125	0.165	3.18	4.19
D	0.016	0.021	0.407	0.533
G	0.045	0.055	1.15	1.39
Н	0.095	0.105	2.42	2.66
J	0.015	0.020	0.39	0.50
K	0.500		12.70	
L	0.250		6.35	
N	0.080	0.105	2.04	2.66
P		0.100		2.54
R	0.115		2.93	
٧	0.135		3.43	

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